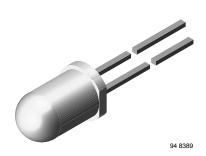
HALOGEN FREE

GREEN



Vishay Semiconductors

High Power Infrared Emitting Diode, 940 nm, GaAlAs, MQW



DESCRIPTION

TSAL6200 is an infrared, 940 nm emitting diode in GaAlAs multi quantum well (MQW) technology with high radiant power and high speed molded in a blue-gray plastic package.

FEATURES

Package type: leaded
Package form: T-1¾

• Dimensions (in mm): Ø 5

• Peak wavelength: $\lambda_p = 940 \text{ nm}$

· High reliability

• High radiant power

· High radiant intensity

• Angle of half intensity: $\varphi = \pm 17^{\circ}$

· Low forward voltage

· Suitable for high pulse current operation

· Good spectral matching with Si photodetectors

 Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Infrared remote control units with high power requirements
- Free air transmission systems
- · Infrared source for optical counters and card readers

| PRODUCT SUMMARY | | | | | |
|-----------------|------------------------|---------|---------------------|---------------------|--|
| COMPONENT | I _e (mW/sr) | φ (deg) | λ _p (nm) | t _r (ns) | |
| TSAL6200 | 72 | ± 17 | 940 | 15 | |

Note

· Test conditions see table "Basic Characteristics"

| ORDERING INFORMATION | | | | |
|----------------------|-----------|------------------------------|--------------|--|
| ORDERING CODE | PACKAGING | REMARKS | PACKAGE FORM | |
| TSAL6200 | Bulk | MOQ: 4000 pcs, 4000 pcs/bulk | T-1¾ | |

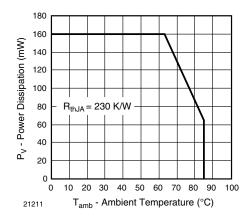
Note

MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) | | | | |
|---|---------------------------------------|-------------------|-------------|------|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
| Reverse voltage | | V_{R} | 5 | V |
| Forward current | | I _F | 100 | mA |
| Peak forward current | $t_p/T = 0.5, t_p = 100 \mu s$ | I _{FM} | 200 | mA |
| Surge forward current | t _p = 100 μs | I _{FSM} | 1.5 | Α |
| Power dissipation | | P_V | 160 | mW |
| Junction temperature | | Tj | 100 | °C |
| Operating temperature range | | T _{amb} | -40 to +85 | °C |
| Storage temperature range | | T _{stg} | -40 to +100 | °C |
| Soldering temperature | t ≤ 5 s, 2 mm from case | T _{sd} | 260 | °C |
| Thermal resistance junction/ambient | J-STD-051, leads 7 mm soldered on PCB | R _{thJA} | 230 | K/W |



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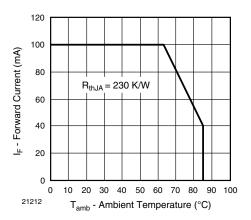


Fig. 2 - Forward Current Limit vs. Ambient Temperature

| BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | |
|--|---|------------------|------|------|------|-------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Forward voltage | $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ | V _F | | 1.35 | 1.6 | V |
| | $I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$ | V _F | | 2.2 | 3 | V |
| Temperature coefficient of V _F | I _F = 1 mA | TK _{VF} | | -1.8 | | mV/K |
| Reverse current | V _R = 5 V | I _R | | | 10 | μΑ |
| Junction capacitance | V _R = 0 V, f = 1 MHz, E = 0 | C _j | | 40 | | pF |
| Prodication and | $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ | l _e | 40 | 72 | 200 | mW/sr |
| Radiant intensity | $I_F = 1 A$, $t_p = 100 \mu s$ | l _e | 340 | 600 | | mW/sr |
| Radiant power | $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ | фe | | 40 | | mW |
| Temperature coefficient of φ _e | I _F = 20 mA | TKφ _e | | -0.6 | | %/K |
| Angle of half intensity | | φ | | ± 17 | | deg |
| Peak wavelength | I _F = 100 mA | λρ | | 940 | | nm |
| Spectral bandwidth | I _F = 100 mA | Δλ | | 30 | | nm |
| Temperature coefficient of λ_p | I _F = 100 mA | TKλ _p | | 0.2 | | nm/K |
| Rise time | I _F = 100 mA | t _r | | 15 | | ns |
| Fall time | I _F = 100 mA | t _f | | 15 | | ns |



BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

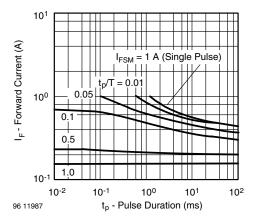


Fig. 3 - Pulse Forward Current vs. Pulse Duration

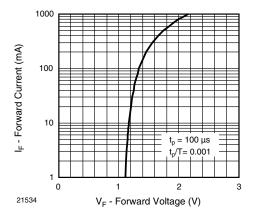


Fig. 4 - Forward Current vs. Forward Voltage

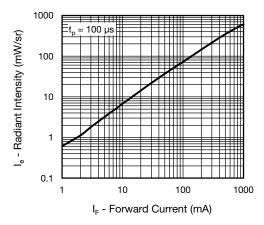


Fig. 5 - Radiant Intensity vs. Forward Current

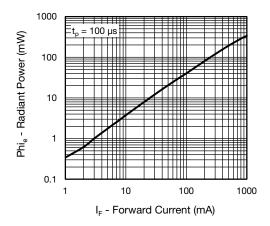


Fig. 6 - Radiant Power vs. Forward Current

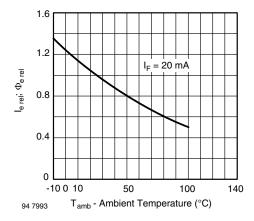


Fig. 7 - Relative Radiant Intensity/Power vs. Ambient Temperature

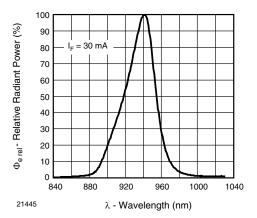


Fig. 8 - Relative Radiant Power vs. Wavelength





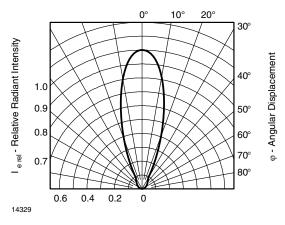
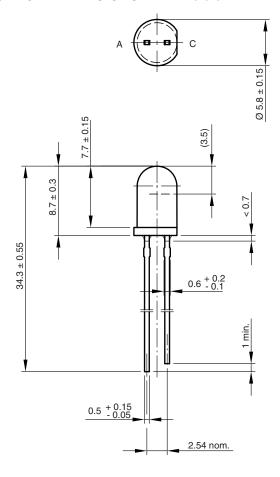
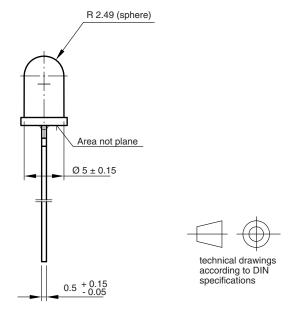


Fig. 9 - Relative Radiant Intensity vs. Angular Displacement

PACKAGE DIMENSIONS in millimeters





Drawing-No.: 6.544-5259.06-4

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